

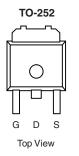
N-Channel 60-V (D-S) MOSFET

| PRODUCT | SUMMARY | |
|---------------------|----------------------------------|---------------------------------|
| V _{DS} (V) | r _{DS(on)} (Ω) | I _D (A) ^a |
| 60 | 0.025 at V _{GS} = 10 V | 45 |
| | 0.030 at V _{GS} = 4.5 V | 40 |

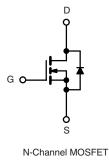
FEATURES

- TrenchFET[®] Power MOSFET
- 175 °C Junction Temperature





Drain Connected to Tab

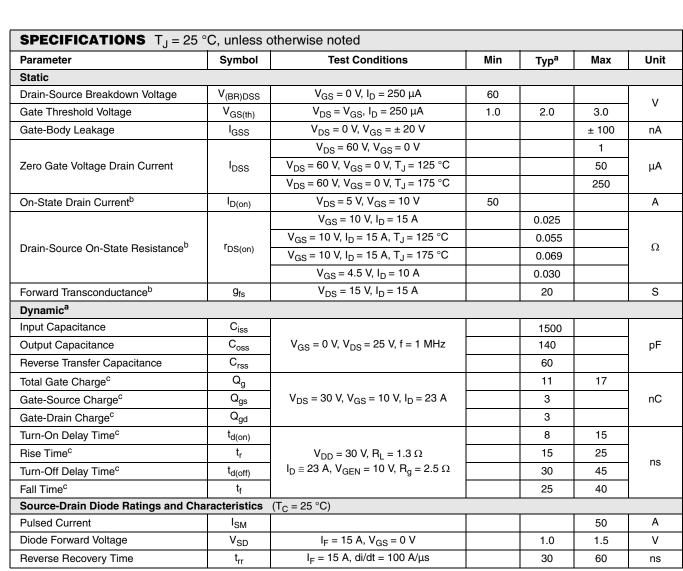


| ABSOLUTE MAXIMUM RATINGS $T_{C} = 2$ | 5 °C, unless othe | rwise noted | | |
|---|-------------------------|-----------------------------------|----------------|------|
| Parameter | | Symbol | Limit | Unit |
| Gate-Source Voltage | | V _{GS} | ± 20 | V |
| Continuous Drain Current (T 175 °C)b | T _C = 25 °C | | 45 | |
| Continuous Drain Current (T _J = 175 °C) ^b | T _C = 100 °C | D | 35 | |
| Pulsed Drain Current | | I _{DM} | 100 | A |
| Continuous Source Current (Diode Conduction) | | ۱ _S | 23 | |
| Avalanche Current | | I _{AS} | 20 | |
| Single Avalanche Energy (Duty Cycle \leq 1 %) | L = 0.1 mH | E _{AS} | 20 | mJ |
| Maximum Dravinsking | T _C = 25 °C | - P _D | 100 | w |
| Maximum Power Dissipation | T _A = 25 °C | ۲D | 3 ^a | vv |
| Operating Junction and Storage Temperature Range | • | T _J , T _{stg} | - 55 to 175 | °C |

| THERMAL RESISTANCE RATINGS | | | | | |
|--|------------------------|-------------------|---------|---------|------|
| Parameter | | Symbol | Typical | Maximum | Unit |
| Maximum Junction-to-Ambient ^a | $t \le 10 \text{ sec}$ | R _{thJA} | 18 | 22 | °C/W |
| Maximum Junction-to-Ambient* | Steady State | | 40 | 50 | |
| Maximum Junction-to-Case | | R _{thJC} | 3.2 | 4 | |

Notes:

a. Surface Mounted on 1" x 1" FR4 board, t \leq 10 sec.



Notes:

a. For design aid only; not subject to production testing.

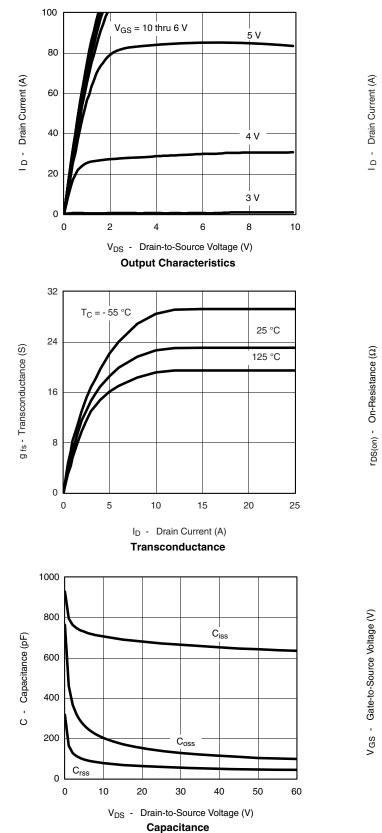
b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

c. Independent of operating temperature.

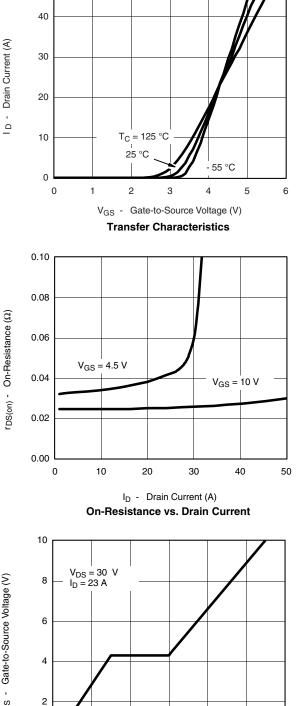
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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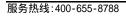


TYPICAL CHARACTERISTICS 25 °C unless noted



Qg - Total Gate Charge (nC)

Gate Charge





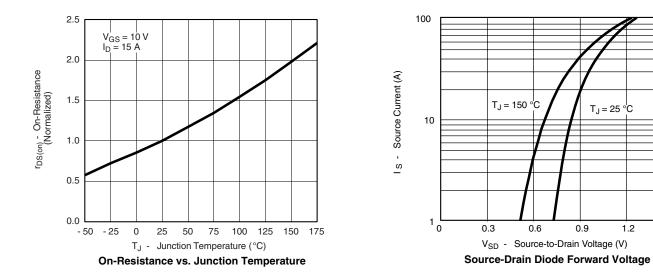
 $T_J = 25 \degree C$

1.2

1.5

0.6

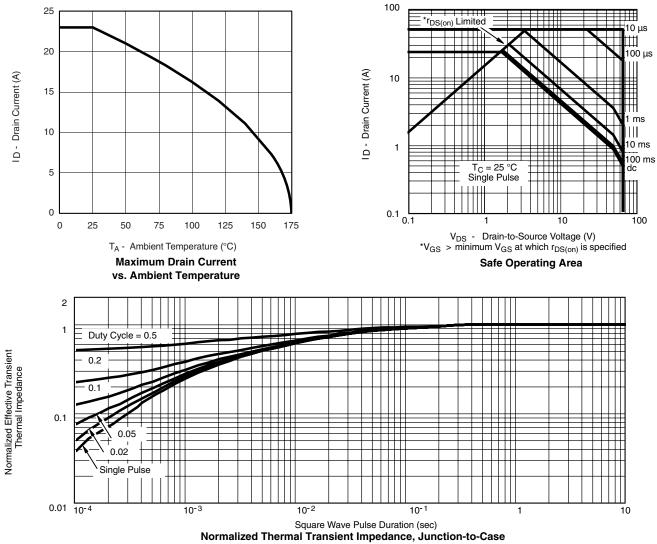
0.9



TYPICAL CHARACTERISTICS 25 °C unless noted

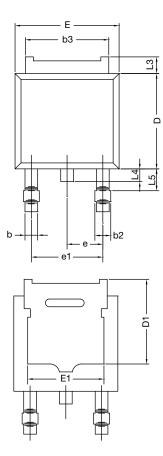


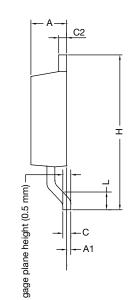
THERMAL RATINGS





TO-252AA CASE OUTLINE





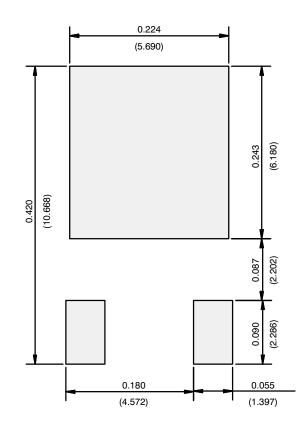
| | MILLIN | MILLIMETERS | | INCHES | | |
|-----------------------|-------------------|-------------|-----------|-----------|--|--|
| DIM. | MIN. | MAX. | MIN. | MAX. | | |
| А | 2.18 | 2.38 | 0.086 | 0.094 | | |
| A1 | - | 0.127 | - | 0.005 | | |
| b | 0.64 | 0.88 | 0.025 | 0.035 | | |
| b2 | 0.76 | 1.14 | 0.030 | 0.045 | | |
| b3 | 4.95 | 5.46 | 0.195 | 0.215 | | |
| С | 0.46 | 0.61 | 0.018 | 0.024 | | |
| C2 | 0.46 | 0.89 | 0.018 | 0.035 | | |
| D | 5.97 | 6.22 | 0.235 | 0.245 | | |
| D1 | 5.21 | - | 0.205 | - | | |
| Е | 6.35 | 6.73 | 0.250 | 0.265 | | |
| E1 | 4.32 | - | 0.170 | - | | |
| Н | 9.40 | 10.41 | 0.370 | 0.410 | | |
| е | 2.28 | BSC | 0.090 BSC | | | |
| e1 | 4.56 | 4.56 BSC | | 0.180 BSC | | |
| L | 1.40 | 1.78 | 0.055 | 0.070 | | |
| L3 | 0.89 | 1.27 | 0.035 | 0.050 | | |
| L4 | - | 1.02 | - | 0.040 | | |
| L5 | 1.14 | 1.52 | 0.045 | 0.060 | | |
| ECN: X12- DWG: 534 | 0247-Rev. M, 7 | 24-Dec-12 | | | | |

Note

• Dimension L3 is for reference only.



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)



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